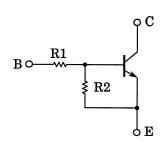
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1321A,RN1322A,RN1323A,RN1324A RN1325A,RN1326A,RN1327A

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

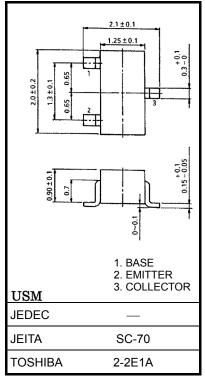
- High current driving is possible.
- Since bias resisters are built in the transistor, the miniaturization of the apparatus by curtailment of the number of parts and laborsaving of an assembly are possible.
- Many kinds of resistance value are lined up in order to support various kinds of circuit design.
- Complementary to RN2321A~RN2327A
- Low V_{CE(sat)} enable to be low power dissipation on high current driving.

Equivalent Circuit And Bias Resistance Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1321A	1	1
RN1322A	2.2	2.2
RN1323A	4.7	4.7
RN1324A	10	10
RN1325A	0.47	10
RN1326A	1	10
RN1327A	2.2	10

Unit: mm



Weight: 0.006 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Collector-base voltage	RN1321A~1327A	V _{CBO}	15	V	
Collector-emitter voltage	1011021A 1021A	V _{CEO}	12	V	
Emitter-base voltage	RN1321A~1324A		10	V	
	RN1325A, 1326A	V_{EBO}	5		
	RN1327A	RN1327A			
Collector current		IC	500	mA	
Collector power dissipation	RN1321A~1327A	PC	100	mW	
Junction temperature	KIN 132 IA~ 132 IA	Tj	150	°C	
Storage temperature range		T _{stg}	−55~150	°C	

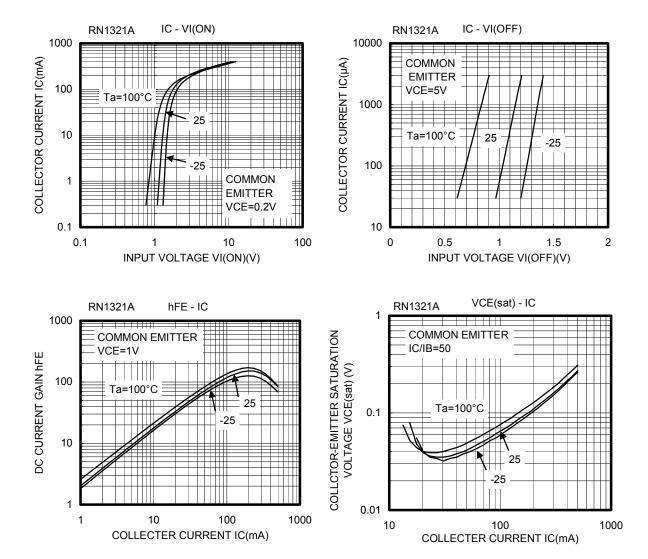
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

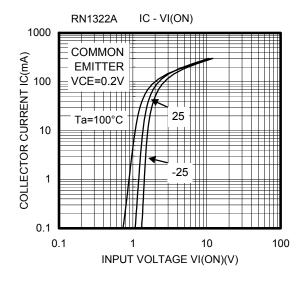
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

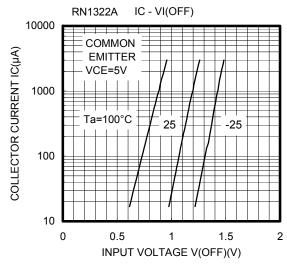


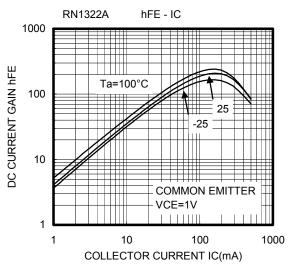
Electrical Characteristics (Ta = 25°C)

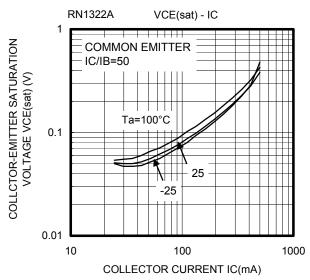
Characte	eristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1321A~1327A	I _{CBO}	_	V _{CB} = 15V, I _E = 0	_	-	100	- nA
	KWIOZIA IOZIA			V _{CE} = 12V, I _B = 0	_	-	500	
Emitter cut-off current	RN1321A	I _{EBO}	_	V _{EB} = 10V, I _C = 0	3.85	-	7.14	
	RN1322A				1.75	-	3.25	
	RN1323A				0.82	_	1.52	
	RN1324A				0.38	_	0.71	mA
	RN1325A			V _{EB} = 5V, I _C = 0	0.365	_	0.682	
	RN1326A				0.35	_	0.65	
	RN1327A			V _{EB} = 6V, I _C = 0	0.378		0.703	
	RN1321A				35	_	_	
	RN1322A				65	_	_	
	RN1323A				100	_	_	
DC current gain	RN1324A	h _{FE}	_	V _{CE} = 1V, I _C = 50mA	140	_	_	
	RN1325A			JE 11,10 301111	140	_	_	
	RN1326A				140	_	_	
	RN1327A				140	_	_	
Collector-emitter	RN1321A			I _C = 50mA, I _B = 2mA				
saturation voltage	RN1322A~1327A	V _{CE} (sat)	_	I _C = 50mA, I _B = 1mA	_	_	0.25	V
	RN1321A	V _I (ON)		V _{CE} = 0.2V, I _C = 50mA	1.0	_	2.4	V
Input voltage (ON)	RN1322A		_		1.1	_	2.7	
	RN1323A				1.3	_	3.5	
	RN1324A				1.5	_	5.2	
	RN1325A				0.5	_	1.2	
	RN1326A				0.6	_	1.4	
	RN1327A				0.7	_	1.9	
	RN1321A~1324A	V _{I (OFF)}	_	V _{CE} = 5V, I _C = 0.1mA	0.8	_	1.4	V
Input voltage (OFF)	RN1325A, 1326A				0.4	_	0.8	
	RN1327A				0.5	_	1.0	
Transition frequency	RN1321A~1327A	f _T	_	V _{CE} = 5V, I _C = 20mA	_	300	_	MHz
Collector Output capacitance	RN1321A~1327A	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MH _z	_	4	_	pF
Input resistor	RN1321A	R1	_	_	0.7	1	1.3	
	RN1322A				1.54	2.2	2.86	
	RN1323A				3.29	4.7	6.11	
	RN1324A				7	10	13	kΩ
	RN1325A				0.329	0.47	0.611	
	RN1326A				0.7	1	1.3	
	RN1327A				1.54	2.2	2.86	
Resistor ratio	RN1321A~1324A			_	0.85	1.00	1.15	
	RN1325A				0.040	0.047	0.054	
	RN1326A	R1/R2	_		0.085	0.100	0.115	
	RN1327A				0.187	0.220	0.253	!

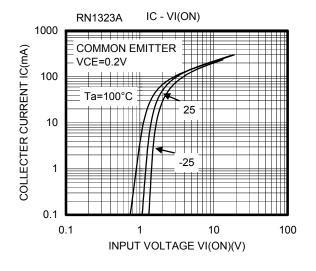


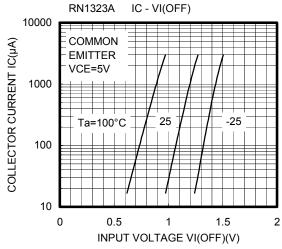


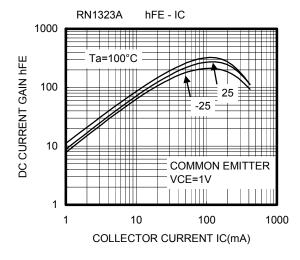


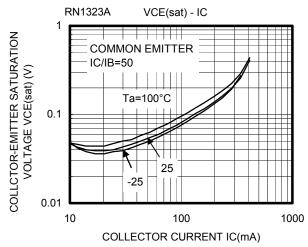


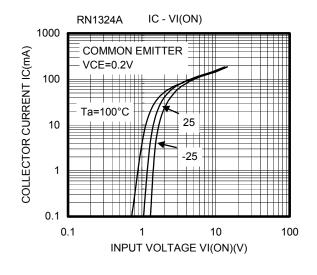


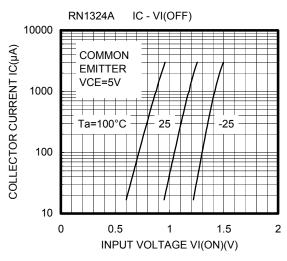


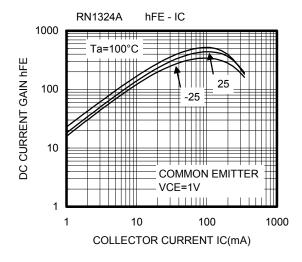


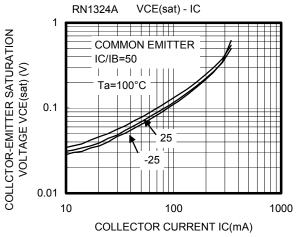




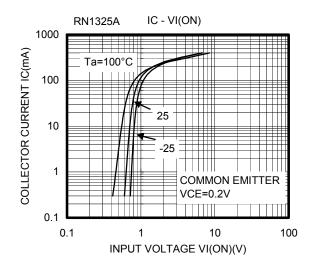


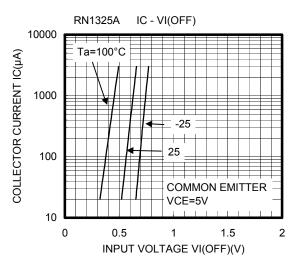


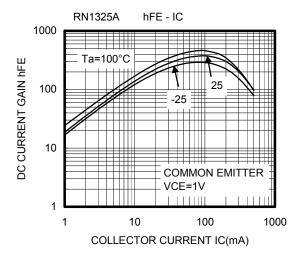


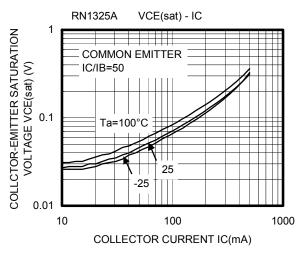


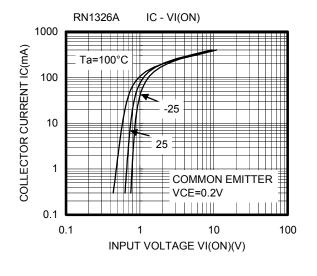
2007-11-01

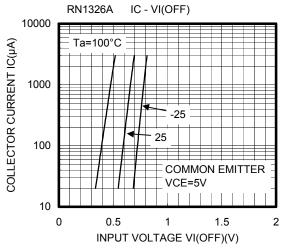


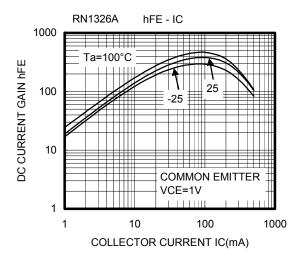


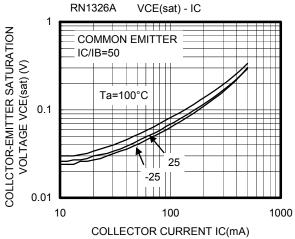




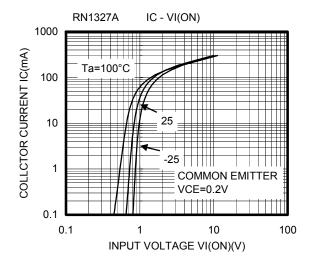


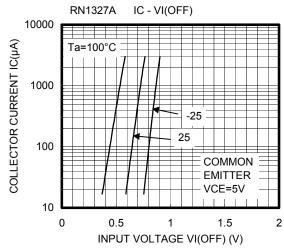


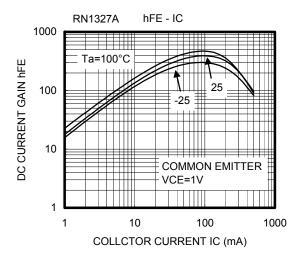


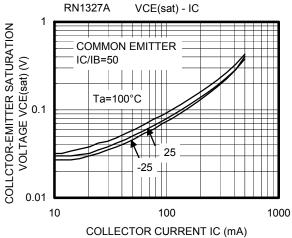


2007-11-01









Type Name	Marking
RN1321A	Type Name Q A
RN1322A	Type Name Q B
RN1323A	Type Name
RN1324A	Type Name Q D
RN1325A	Type Name QE
RN1326A	Type Name Q F
RN1327A	Type Name Q G

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patents or other rights of TOSHIBA or the third parties.
- Please contact your sales representative for product-by-product details in this document regarding RoHS
 compatibility. Please use these products in this document in compliance with all applicable laws and regulations
 that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses
 occurring as a result of noncompliance with applicable laws and regulations.